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Dual N-Channel 20 V (D-S) MOSFET

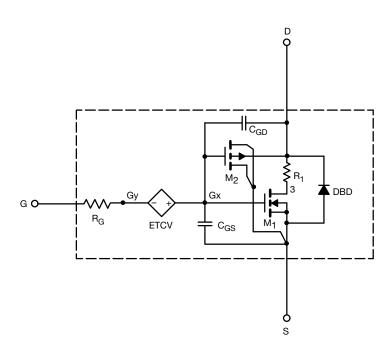
DESCRIPTION

The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to + 125 °C temperature ranges under the pulsed 0 V to 5 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage. A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

SUBCIRCUIT MODEL SCHEMATIC

CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- · Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



SPICE Device Model Si1922EDH

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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	0.50	-	V
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 1 \text{ A}$	0.165	0.165	Ω
		V _{GS} = 2.5 V, I _D = 1 A	0.188	0.187	
Forward Transconductancea	9 _{fs}	$V_{DS} = 4 \text{ V}, I_D = 1.5 \text{ A}$	5	4	S
Diode Forward Voltage	V_{SD}	I _S = 1.2 A	0.80	0.80	V
Dynamic ^b					
Total Gate Charge	Q _g Q _{gs} Q _{gd}	$V_{DS} = 10 \text{ V}, V_{GS} = 8 \text{ V}, I_D = 1.5 \text{ A}$	0.73	1.6	
			0.44	0.90	nC
Gate-Source Charge		$V_{DS} = 10 \text{ V}, V_{GS} = 4.5, I_D = 1.5 \text{ A}$	0.10	0.10	nc nc
Gate-Drain Charge			0.20	0.20	

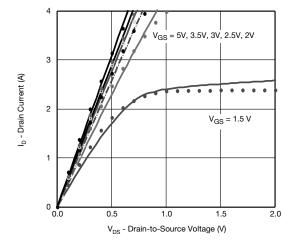
Notes

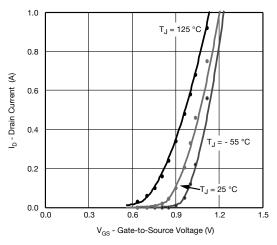
- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

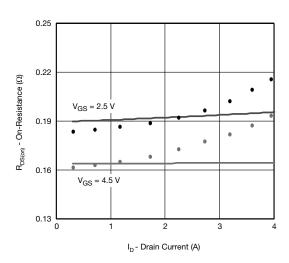
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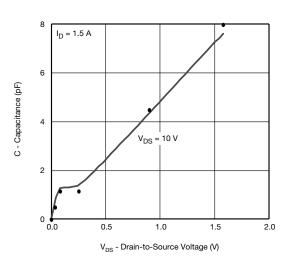
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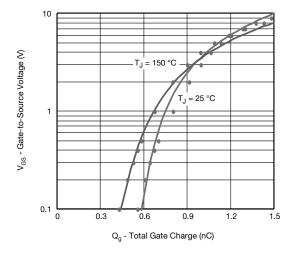
COMPARISON OF MODEL WITH MEASURED DATA $T_J = 25~^{\circ}\text{C}$, unless otherwise noted

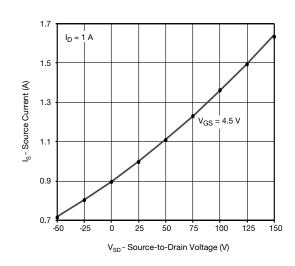












Note

• Dots and squares represent measured data.





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